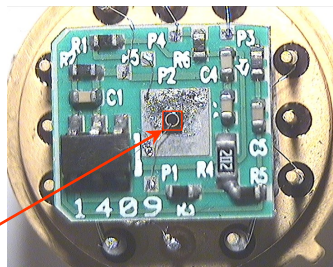
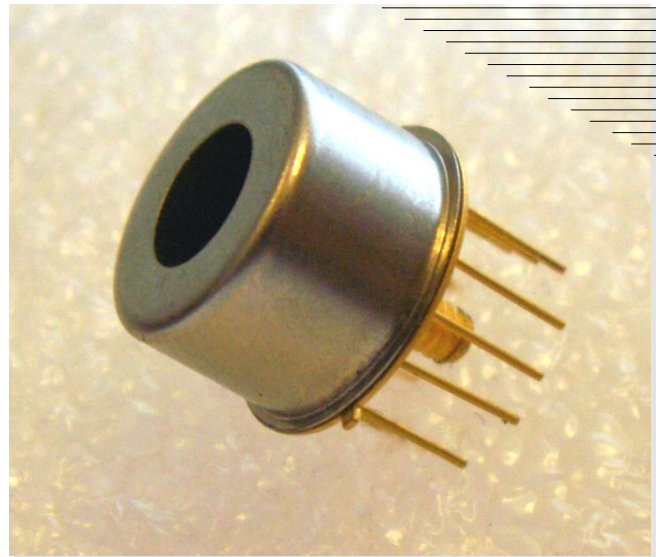


## Features

- High sensitivity
- High reliability
- Superior linearity
- Thermo stability



Photodiode CHIP



## Applications

- Optical measurement equipment
- Analytical instruments

## Description

Photodiode amplifier with TEC **AMP24-05** is a model of [photodetector](#), consist of [photodiode](#) PD24-05, pre-amplifier, thermoelectric cooler (TEC) and thermistor for a control of temperature. Components are integrated inside the standard 15.2 mm TO-8 package with TEC.

Photodiode amplifier with TEC **AMP24-05** is designed for detection of radiation in the Middle Infrared (Mid-IR) spectral range from 1150 to 2400 nm. [Heterostructures](#) with the InGaAsSb active layer and the AlGaAsSb "window" are grown on GaSb substrates.

Diameter of the photosensitive area of **AMP24-05** is 500  $\mu\text{m}$ . Fast response makes it possible for detection of modulated radiation of laser diodes (LDs) and light-emitting diodes (LEDs).

Related products: **AMP24-05** can be used in optical pair with our [LED11...LED23](#) and [LD200...LD230](#).

## General characteristics

Package	Parameter	Symbol	Value	Unit
TO-8 with TEC	Sensitive area diameter	d	0.5	mm
	Weight	m	4.0	g
	Operating temperature	T <sub>opr</sub>	0...+30	°C
	Window material	Sapphire glass		
	Cooling	One-stage TE-cooled		
	Soldering temperature	T <sub>s</sub>	230	°C
	Storage temperature	T <sub>stg</sub>	-20...+40	°C
	Size	D	15.2	mm
H		16		

▼ **Electrical and optical characteristics (absolute maximum values at +20°C)**

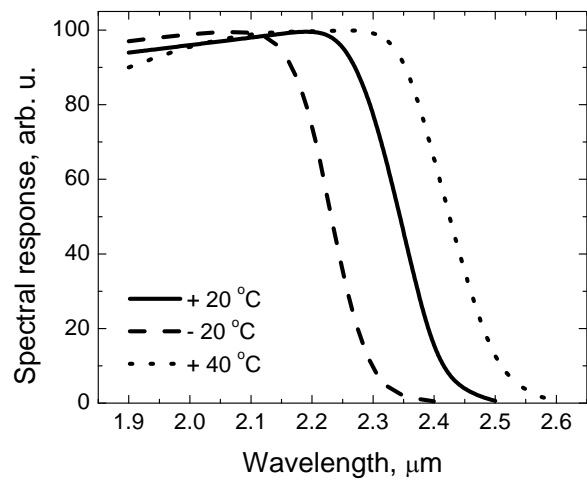
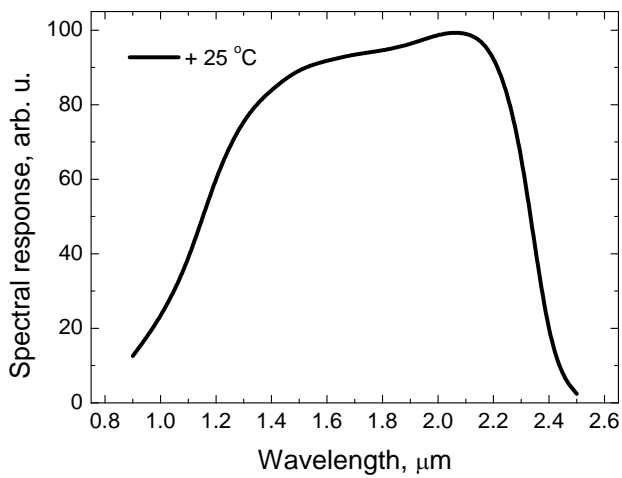
Parameter	Symbol	Value	Unit
Spectral sensitivity range (at level 10%)	$\lambda$	1.15-2.40	$\mu\text{m}$
Peak sensitivity wavelength	$\lambda_p$	2.0-2.2	$\mu\text{m}$
Volt sensitivity	$S_v$	$4 \cdot 10^4$	V/A
Detection threshold (at $\lambda_{\text{max}}$ )	P	$10^{-7}$	W
Detectivity	$D^*$	$[0.7-1.0] \cdot 10^{11}$	$\text{cm} \cdot \text{Hz}^{-1/2} \cdot \text{W}^{-1}$
Frequency range	$\Delta f$	0.15-350	kHz
Rise time	$t_r$	1	$\mu\text{s}$
Fall time	$t_f$	1	$\mu\text{s}$
Output impedance	R	20	$\Omega$
Maximal amplitude of output signal	$V_{\text{amp}}$	<5	V
External power supply	$V_p$	5-6 (stabilized)	V
Output noise voltage (peak to peak at $\Delta f \approx 350$ kHz)	$V_N$	3	mV
Output signal		AC	
Output polarity		Negative	

▼ **TEC 1MC06-018-08 parameters (without load)**

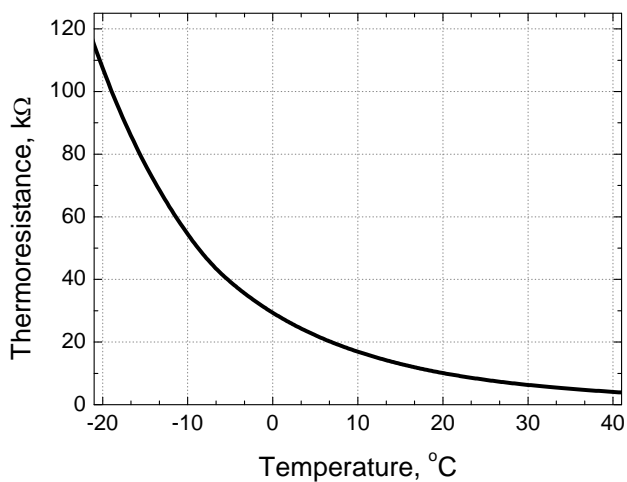
Parameter	Symbol	Value	Unit
Current ( $\Delta T_{\text{max}}$ )	$I_{\text{max}}$	2.20	A
Voltage ( $\Delta T_{\text{max}}$ )	$U_{\text{max}}$	2.20	V
Cooling energy	$Q_{\text{max}}$	2.65	W
Temperature range (vacuum)	$\Delta T_{\text{max}}$	70	K
Thermistor resistance (+20°C)	$R_t$	10.00	k $\Omega$

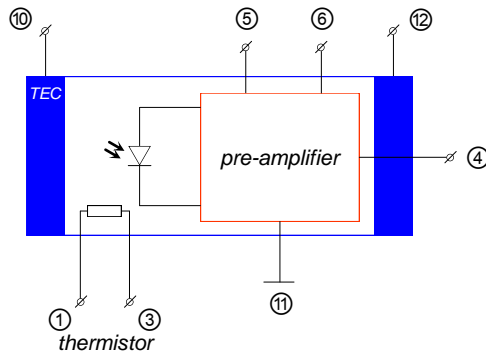
\* Recommend to use all capacitances type of TKE: "X7R"

▼ **Spectral response**



▼ **Thermoresistance vs. temperature**



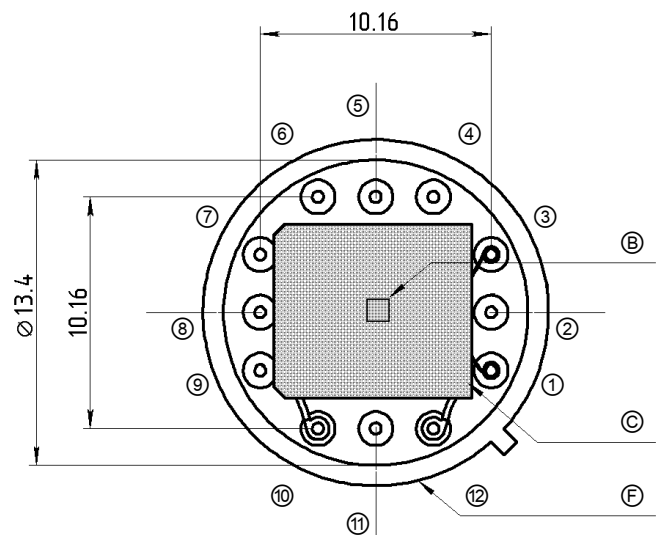
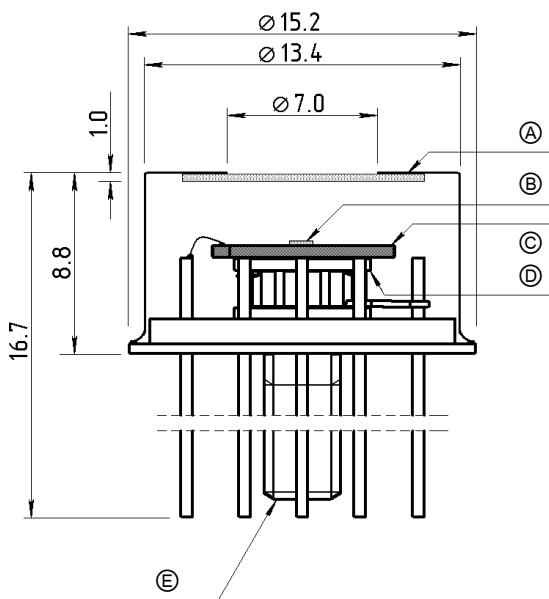


Pin	Description
①	Thermistor TC103
③	
④	Signal output
⑤	+ 5 V
⑥	0 V
⑩	TEC -
⑫	TEC +
⑪	GND
②, ⑦, ⑧, ⑨	Not applicable

▼ Package dimensions (unit: mm)

PROFILE SIDE VIEW

TOP SIDE VIEW (without cap)



- Ⓐ WINDOW
- Ⓑ Photodiode CHIP
- Ⓒ Pre-amplifier

- Ⓓ TEC 1MC06-018-08
- Ⓔ 4-40 UNC
- Ⓕ TO-8 12 pin header

